

**Pb Free Plating Product****FFB10UP20STM**

10Amperes,200Volts Single Surface Mount Ultra Fast Recovery Epitaxial Diode

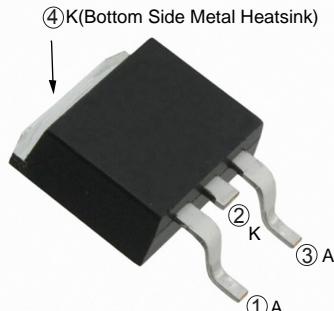
**APPLICATION**

- Freewheeling, Snubber, Clamp
- Inversion Welder
- PFC
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- UPS

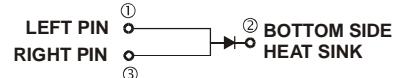
**PRODUCT FEATURE**

- Ultrafast Recovery Time
- Soft Recovery Characteristics
- Low Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Leakage Current

TO-263/D2PAK(SMD-220)



Internal Configuration



Note: Pins Left & Right must  
be electrically connected  
at the printed circuit board.

**GENERAL DESCRIPTION**

FFB10UP20STM using the latest FRED FAB process(planar passivation pellet) with ultrafast and soft recovery characteristics.

**Absolute Maximum Ratings** (per diode)  $T_a = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Value	Units
$V_{RRM}$	Peak Repetitive Reverse Voltage	200	V
$V_{RWM}$	Working Peak Reverse Voltage	200	V
$V_R$	DC Blocking Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 120^\circ\text{C}$	10	A
$I_{FSM}$	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	100	A
$T_J, T_{STG}$	Operating Junction and Storage Temperature	-65 to +150	°C

**Thermal Characteristics**  $T_a = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Max	Units
$R_{JJC}$	Maximum Thermal Resistance, Junction to Case	3.0	°C/W

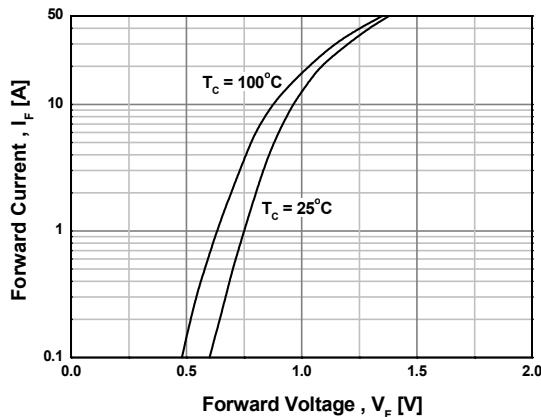
**Electrical Characteristics** (per diode)  $T_a = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Min.	Typ.	Max.	Units
$V_{FM} *$	$I_F = 10\text{A}$ $I_F = 10\text{A}$	$T_C = 25^\circ\text{C}$ $T_C = 150^\circ\text{C}$	- -	- 1.0	V V
$I_{RM} *$	$V_R = 200\text{V}$ $V_R = 200\text{V}$	$T_C = 25^\circ\text{C}$ $T_C = 150^\circ\text{C}$	- -	100 500	$\mu\text{A}$ $\mu\text{A}$
$t_{rr}$	$I_F = 1\text{A}, di/dt = 100\text{A}/\mu\text{s}, V_{CC} = 30\text{V}$ $I_F = 10\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_{CC} = 130\text{V}$	$T_C = 25^\circ\text{C}$ $T_C = 25^\circ\text{C}$	- -	35 45	ns ns
$t_a$ $t_b$ $Q_{rr}$	$I_F = 10\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_{CC} = 130\text{V}$	$T_C = 25^\circ\text{C}$ $T_C = 25^\circ\text{C}$ $T_C = 25^\circ\text{C}$	15 12 36	- - -	ns ns nC
$W_{AVL}$	Avalanche Energy (L = 20mH)	10	-	-	mJ

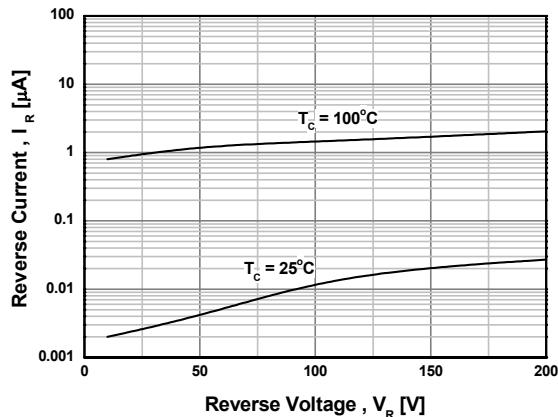
\* Pulse Test: Pulse Width=300μs, Duty Cycle=2%

## Typical Performance Characteristics

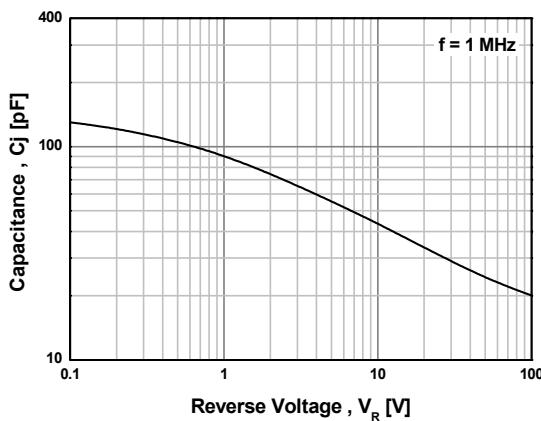
**Figure 1. Typical Forward Voltage Drop**



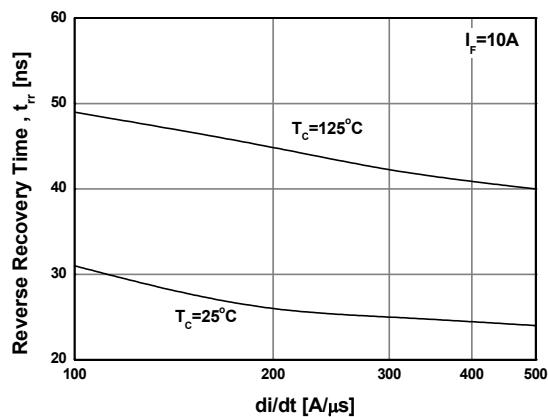
**Figure 2. Typical Reverse Current**



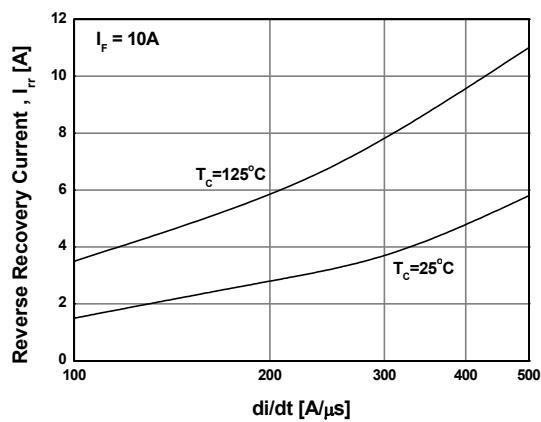
**Figure 3. Typical Junction Capacitance**



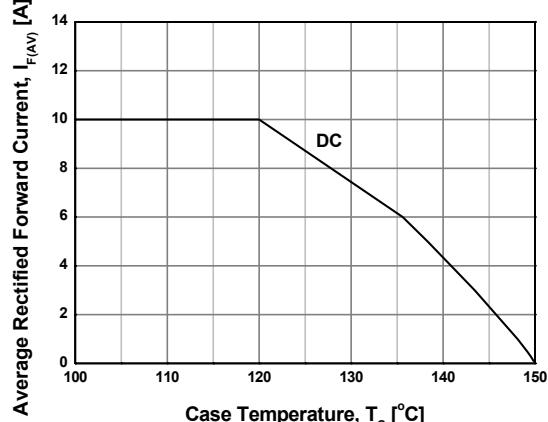
**Figure 4. Typical Reverse Recovery Time**

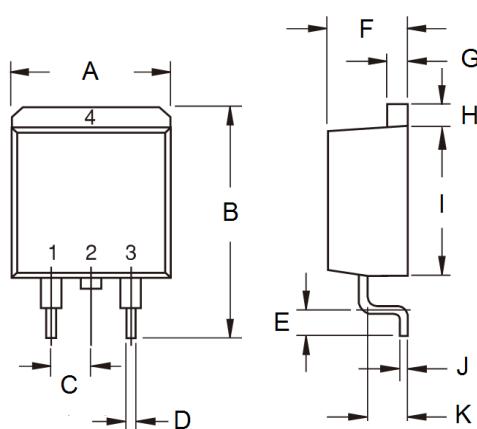


**Figure 5. Typical Reverse Recovery Current**



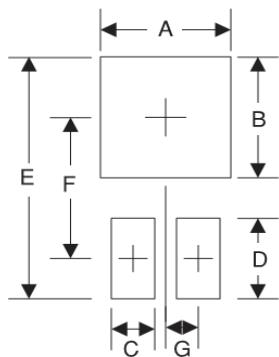
**Figure 6. Forward Current Deration Curve**



PACKAGE OUTLINE DIMENSIONS **TO-263 (D<sup>2</sup>PAK)**

DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	-	10.5	-	0.413
B	14.60	15.88	0.575	0.625
C	2.41	2.67	0.095	0.105
D	0.68	0.94	0.027	0.037
E	2.29	2.79	0.090	0.110
F	4.44	4.70	0.175	0.185
G	1.14	1.40	0.045	0.055
H	1.14	1.40	0.045	0.055
I	8.25	9.25	0.325	0.364
J	0.36	0.53	0.014	0.021
K	2.03	2.79	0.080	0.110

## SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	10.8	0.425
B	8.3	0.327
C	1.1	0.043
D	3.5	0.138
E	16.9	0.665
F	9.5	0.374
G	2.5	0.098